



KBP404G-KBP410G

Product Summary (@T_A = +25°C)

V _{RRM} (V)	I _O MAX (A)	V _F MAX (V)	Ι _R ΜΑΧ (μΑ)	
400, 600, 800, 1000	4	1.1	5	

Description and Applications

Suitable for AC to DC bridge full wave rectification for AC/DC Power Supply, LED lighting, home appliances, office equipment, and telecommunication applications.

4.0A GLASS PASSIVATED BRIDGE RECTIFIER

Features and Benefits

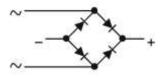
- Glass Passivated Die Construction
- Rating to 1000V PRV
- Low Reverse Leakage Current
- Surge Overload Rating to 130A Peak
- Ideal for Printed Circuit Board Applications
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)

Mechanical Data

- Case: KBP
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Tin. Plated Leads, Solderable per MIL-STD-202, Method 208 44:
- Polarity: Marked on Body
- Weight: 1.52 grams (Approximate)

KBP





Equivalent Circuit

Ordering Information (Note 3)

Part Number	Compliance	Case	Packaging
KBP404G	Commercial	KBP	35 Pieces per Tube
KBP406G	Commercial	KBP	35 Pieces per Tube
KBP408G	Commercial	KBP	35 Pieces per Tube
KBP410G	Commercial	KBP	35 Pieces per Tube

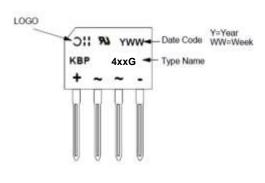
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

Characteristic	Symbol	KBP404G	KBP406G	KBP408G	KBP410G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	400	600	800	1000	V
RMS Reverse Voltage	V _{R(RMS)}	280	420	560	700	V
Average Rectified Output Current @T _C = +105°C (With Heatsink) (Without Heatsink)	lo	4.0 2.0				А
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	130				А
Non-Repetitive Peak Forward Surge Current 1.0ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	260				А
$I^{2}t$ Rating for Fusing (3ms $\leq t \leq 8.3$ ms)	l ² t	50			A ² s	

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance, Junction to Case (Note 4)	R _{θJC}	6	°C/W
Typical Thermal Resistance, Junction to Lead (Note 4)	R _{θJL}	8	°C/W
Typical Thermal Resistance, Junction to Ambient (Note 4)	R _{0JA}	15	°C/W
Typical Thermal Resistance, Junction to Case (Note 5)	R _{θJC}	14	°C/W
Typical Thermal Resistance, Junction to Lead (Note 5)	R _{0JL}	20	°C/W
Typical Thermal Resistance, Junction to Ambient (Note 5)	R _{0JA}	40	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

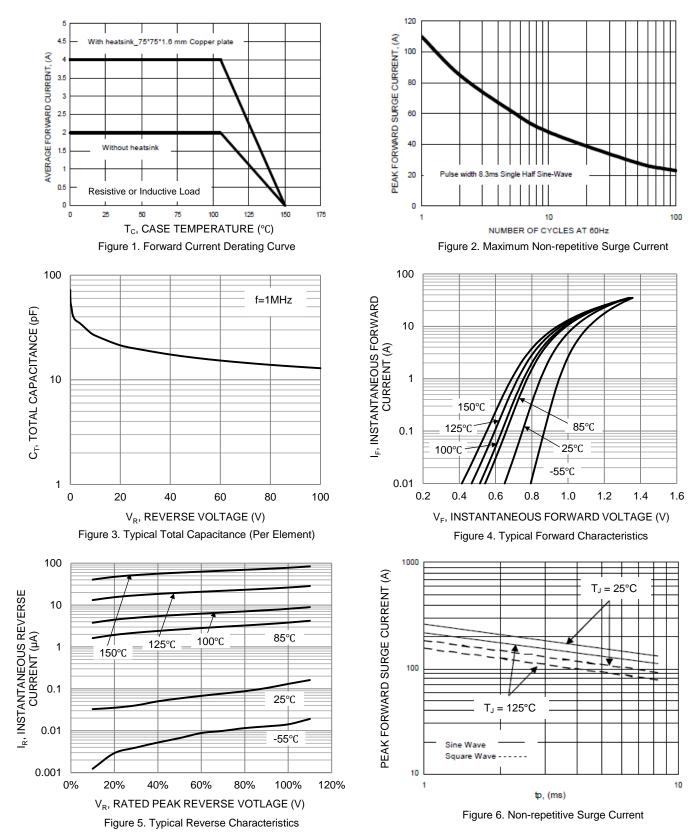
Symbol	Min		Тур	Max	Unit	Test Condition
	1,000	KBP410G				
	800	KBP408G				
V(BR)R	600		_	v	Ι _R = 5μΑ	
	400	KBP404G				
VF	—		0.94	1.1	V	I _F = 4.0A, T _J = +25°C
I _R	_			5 500	μA	V _R = 1000V, T _J = +25°C V _R = 1000V, T _J = +125°C
CT	_		40	_	pF	$V_R = 4.0V_{DC}$, f = 1MHz
	V _{(BR)R} V _F	$V_{(BR)R} = \frac{1,000}{800}$ $V_{(BR)R} = \frac{1,000}{600}$ $\frac{1,000}{600}$ $\frac{1}{400}$ $V_F = \frac{1}{100}$ $V_F = \frac{1}{100}$	V(BR)R 1,000 KBP410G 800 KBP408G 600 KBP406G 400 KBP404G VF — IR —	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{ c c c c c c c c c c c c c c c c c c c$

5. Thermal resistance per element without heatsink.

6. Short duration pulse test used to minimize self-heating effect.



KBP404G-KBP410G



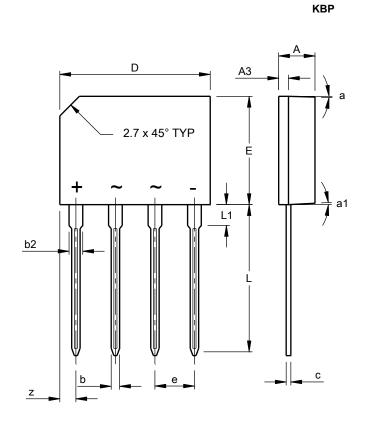
NEW PRODUCT

KBP404G-KBP410G Document number: DS39310 Rev. 2 - 2



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



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KBP						
Dim	Min	Тур				
Α	3.35	3.65	-			
A3	0.80	1.10	-			
b	0.76	0.86	-			
b2	1.22	1.42	-			
С	0.35	0.55	-			
D	14.25	14.75	-			
Е	10.20	10.60	-			
е	3.56	4.06	-			
L	14.25	14.73	-			
L1	1.80	2.20	-			
z	1.40	1.70	-			
а	-	-	3°			
a1	-	-	2°			
All Dimensions in mm						



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